

# INK011AAC1

High Speed Switching  
Silicon N-channel MOSFET

## DESCRIPTION

INK011AAC1 is a Silicon N-channel MOSFET.

This product is most suitable for use such as portable machinery, because of low voltage drive.

## FEATURE

- Input impedance is high, and not necessary to consider a drive electric current.
- High drain current  $I_D=1.4A$
- Drive voltage 4V
- High speed switching.

## APPLICATION

High speed switching, Analog switching

## MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$ )

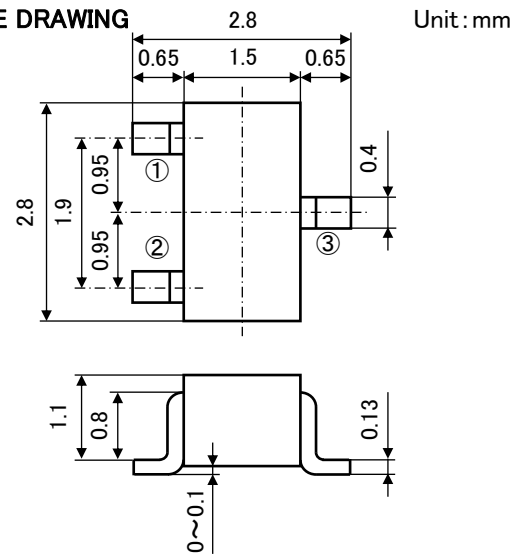
Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	100	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current(DC) (※1)	$I_D$	1.4	A
Drain Current(Pulse) (※2)	$I_{DP}$	3.2	A
Total Power Dissipation (※1)	$P_D$	0.9	W
Channel Temperature	$T_{ch}$	+150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	$-55\sim+150$	$^\circ\text{C}$

※1 package mounted on glass-epoxy substrate.

(39mm×39mm×1.6mm, Cu pad 1500mm<sup>2</sup>)

※2  $P_w \leq 10\text{ms}$ , Duty cycle  $\leq 1\%$

## OUTLINE DRAWING



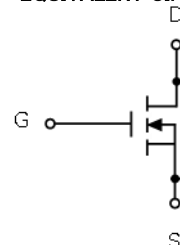
## TERMINAL CONNECTOR

- ①: GATE  
②: SOURCE  
③: DRAIN

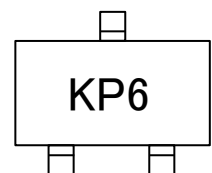
JEITA: SC-59

JEDEC: Similar to TO-236

## EQUIVALENT CIRCUIT



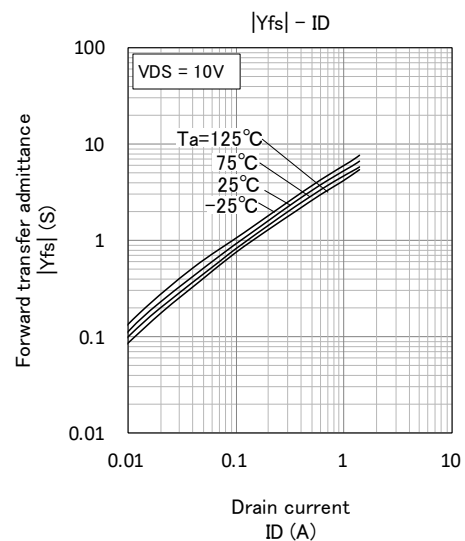
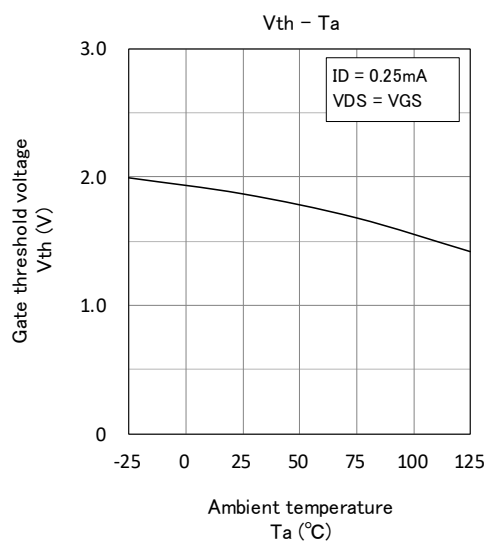
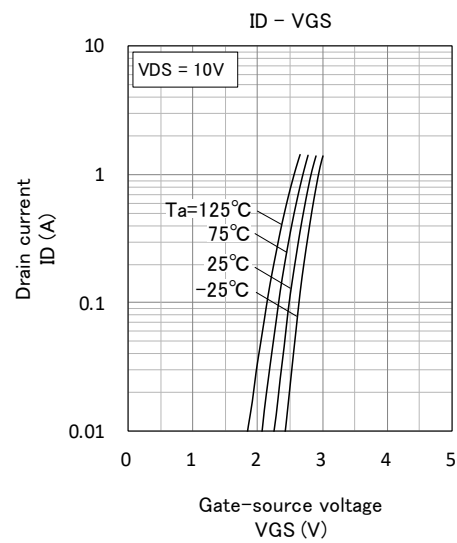
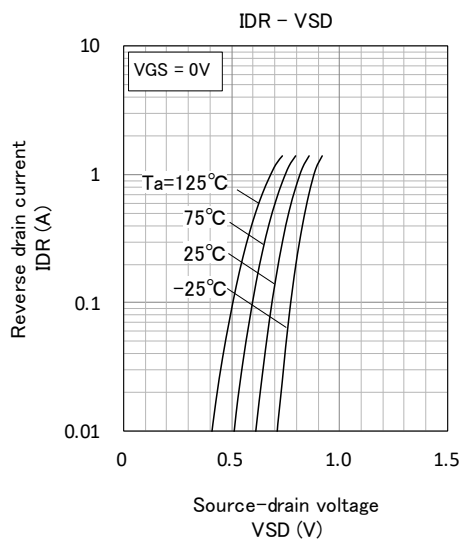
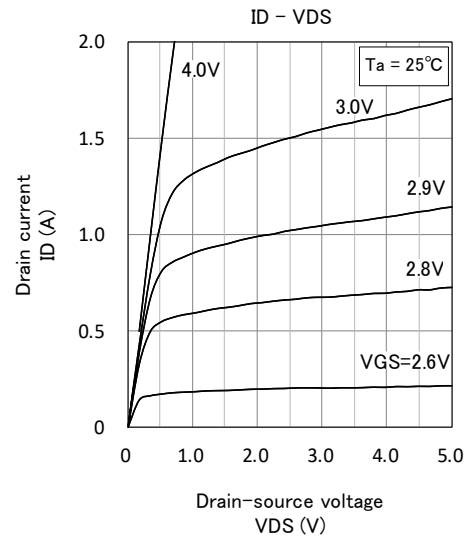
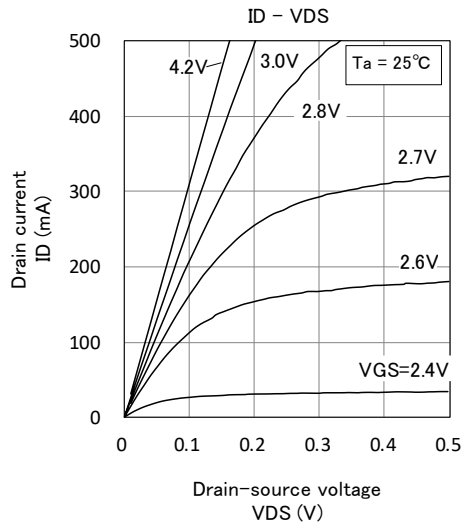
## MARKING



## ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ\text{C}$ )

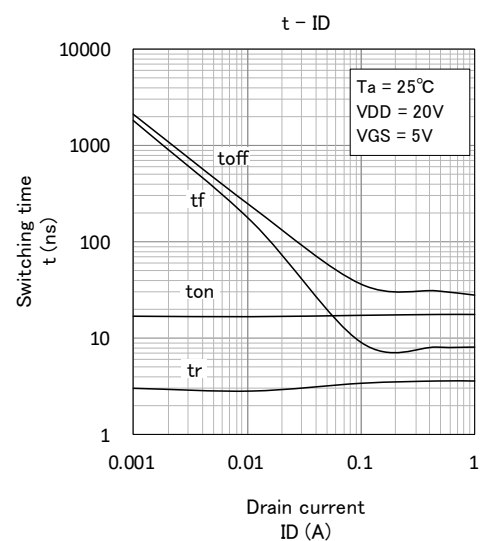
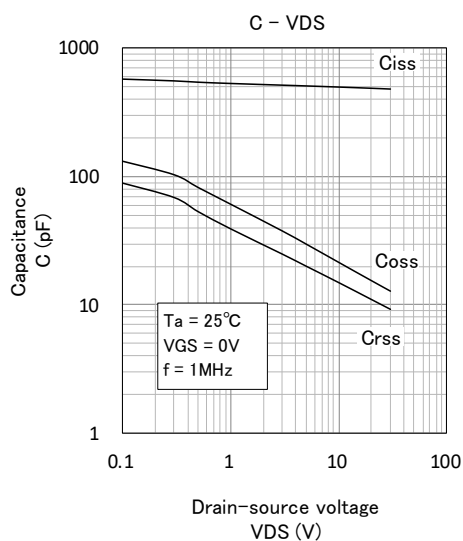
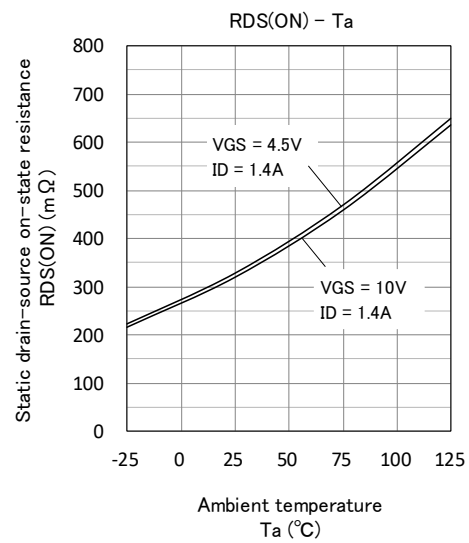
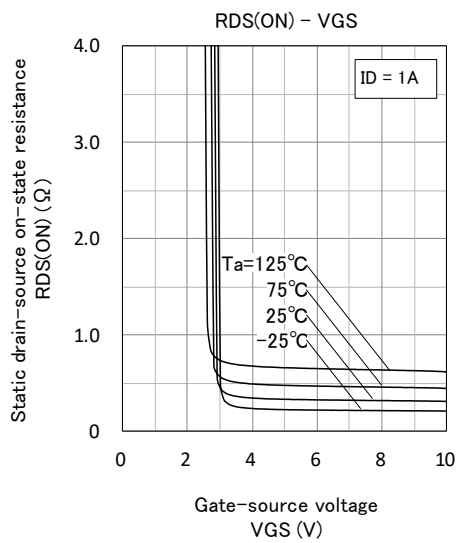
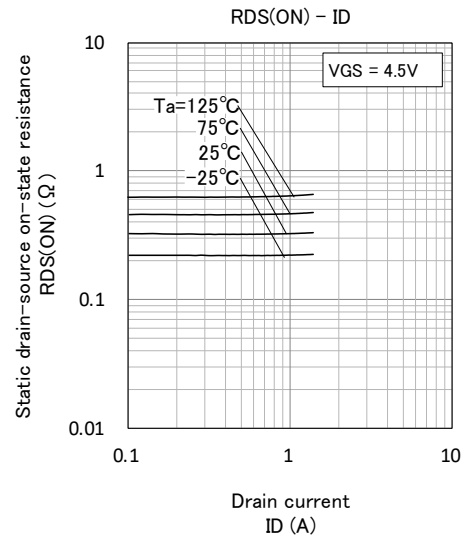
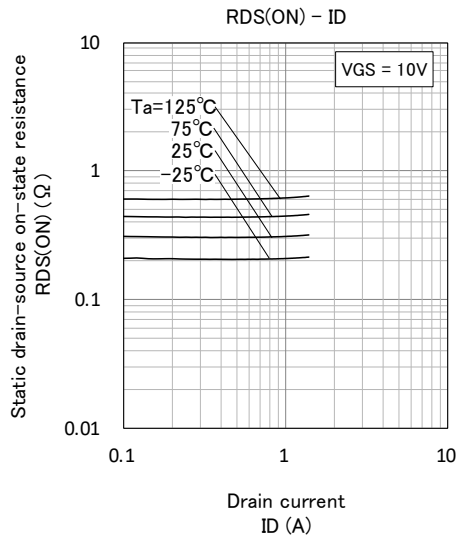
Parameter	Symbol	Test Condition	Limit			Unit
			MIN	TYP	MAX	
Drain-Source Breakdown Voltage	$V_{(BR)DS}$	$I_D=250\mu\text{A}$ , $V_{GS}=0\text{V}$	100	—	—	V
Gate-Source Leak Current	$I_{GSS}$	$V_{GS}=\pm 20\text{V}$ , $V_{DS}=0\text{V}$	—	—	$\pm 1.0$	$\mu\text{A}$
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=100\text{V}$ , $V_{GS}=0\text{V}$	—	—	1.0	$\mu\text{A}$
Gate Threshold Voltage	$V_{th}$	$I_D=250\mu\text{A}$ , $V_{DS}=V_{GS}$	1.0	—	2.5	V
Static Drain-Source On-State Resistance	$R_{DS(ON)}$	$I_D=1.4\text{A}$ , $V_{GS}=4.5\text{V}$	—	323	420	$\text{m}\Omega$
		$I_D=1.4\text{A}$ , $V_{GS}=10\text{V}$	—	311	405	$\text{m}\Omega$
Input Capacitance	$C_{iss}$	$V_{DS}=10\text{V}$ , $V_{GS}=0\text{V}$ , $f=1\text{MHz}$	—	500	—	$\text{pF}$
Output Capacitance	$C_{oss}$		—	21	—	$\text{pF}$
Feedback Capacitance	$C_{rss}$		—	15	—	$\text{pF}$
Switching Time	$t_{on}$	$V_{DD}=20\text{V}$ , $I_D=200\text{mA}$ , $V_{GS}=5\text{V}$	—	18	—	ns
	$t_{off}$		—	34	—	ns

## TYPICAL CHARACTERISTICS



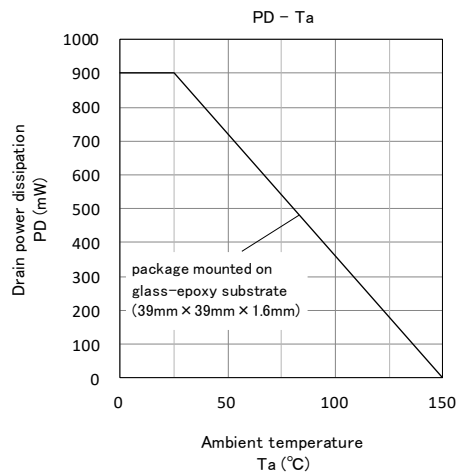
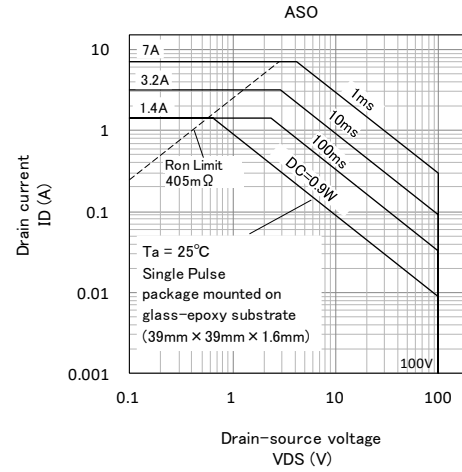
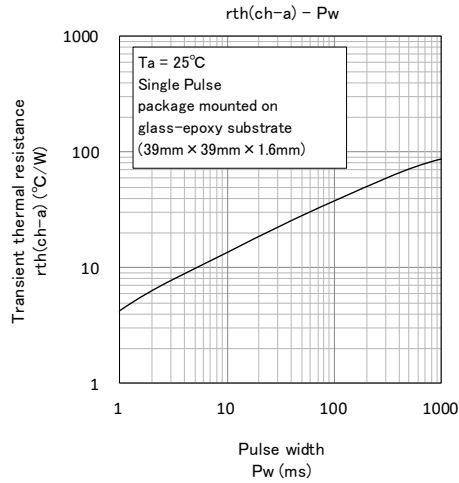
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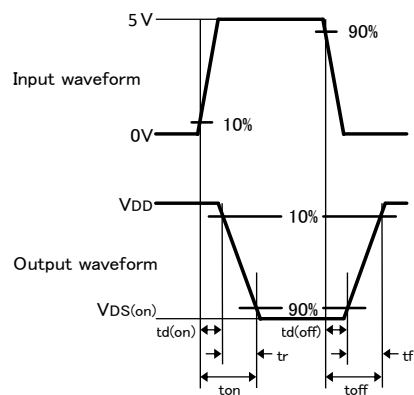
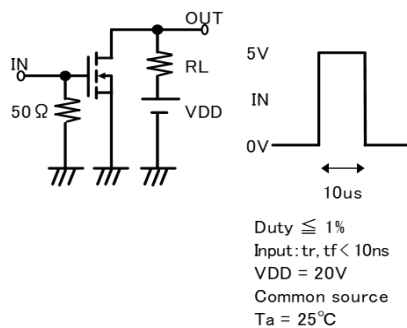


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## Switching time test condition



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